

1. Record Nr.	UNINA9910827956603321
Titolo	Handbook of RF and microwave power amplifiers // edited by John L.B. Walker [[electronic resource]]
Pubbl/distr/stampa	Cambridge : , : Cambridge University Press, , 2012
ISBN	1-107-22450-0 1-139-15259-9 1-283-34222-7 9786613342225 1-139-16002-8 1-139-16102-4 1-139-15546-6 1-139-15721-3 1-139-01534-6
Descrizione fisica	1 online resource (xiii, 687 pages) : digital, PDF file(s)
Collana	The Cambridge RF and microwave engineering series
Classificazione	TEC024000
Disciplina	621.384/12
Soggetti	Power amplifiers Amplifiers, Radio frequency Microwave amplifiers
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Title from publisher's bibliographic system (viewed on 05 Oct 2015).
Nota di bibliografia	Includes bibliographical references and index.
Nota di contenuto	Silicon LDMOS and VDMOS transistors : physics, design, and technology / Wayne Burger and Christopher P. Dragon -- GaAs FETs : physics, design, and models / Rob Davis -- Wide band gap transistors -- SiC and GaN : physics, design and models / Robert J. Trew -- Amplifier classes, A-S / Steve C. Cripps -- Computer-aided design of power amplifiers / Steven Maas -- Practical HF/VHF/UHF RF power amplifier realization / Daniel P. Myer -- Microwave hybrid amplifier realization / Dominic FitzPatrick -- Monolithic power amplifiers / Inder J. Bahl -- RF power amplifier thermal design / Mali Mahalingam -- Reliability / Bill Roesch -- Power amplifier applications / Mustafa Akkul and Wolfgang Bosch -- Amplifier measurements / Michael G. Hiebel.
Sommario/riassunto	Whether you are an RF transistor designer, an amplifier designer or a

system designer, this is your one-stop guide to RF and microwave transistor power amplifiers. A team of expert authors brings you up to speed on every topic, including: devices (Si LDMOS and VDMOS, GaAs FETs, GaN HEMTs), circuit and amplifier design (discrete, hybrid and monolithic), CAD, thermal design, reliability, and system applications/requirements for RF and microwave transistor amplifiers. Covering state-of-the-art developments and emphasising practical communications applications, this is the complete professional reference on the subject.
